74LV4052 Dual 4-channel analog multiplexer/demultiplexer Rev. 4 – 1 July 2013 Pro

Product data sheet

1. General description

The 74LV4052 is a low-voltage CMOS device and is pin and function compatible with the 74HC/HCT4052.

The 74LV4052 is a dual 4-channel analog multiplexer/demultiplexer with a common select logic. Each multiplexer has four independent inputs/outputs (nY0 to nY3) and a common input/output (nZ). The common channel select logics include two digital select inputs (S0 and S1) and an active LOW enable input (\overline{E}). With \overline{E} LOW, one of the four switches is selected (low impedance ON-state) by S0 and S1. With \overline{E} HIGH, all switches are in the high impedance OFF-state, independent of S0 and S1. V_{CC} and GND are the supply voltage pins for the digital control inputs (S0, S1 and \overline{E}). The V_{CC} to GND ranges are 1.0 V to 6.0 V. The analog inputs/outputs (nY0, to nY3, and nZ) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. V_{CC} - V_{EE} may not exceed 6.0 V. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

2. Features and benefits

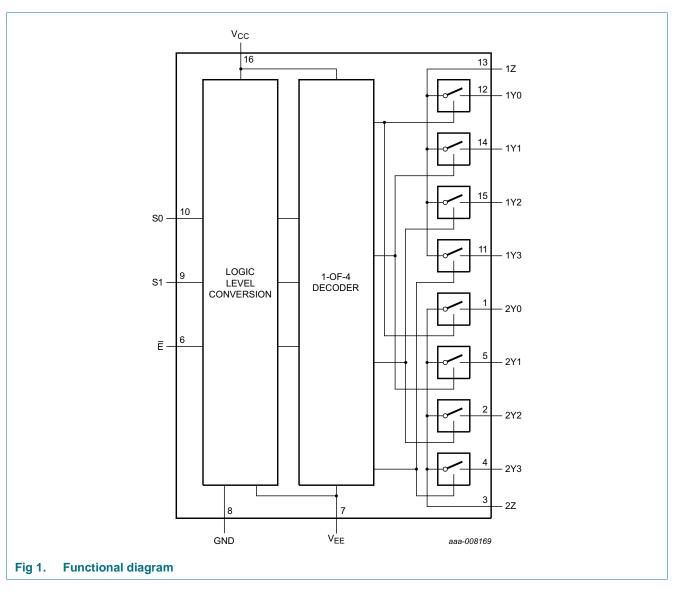
- Optimized for low-voltage applications: 1.0 V to 6.0 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Low ON resistance:
 - 145 Ω (typical) at V_{CC} V_{EE} = 2.0 V
 - 90 Ω (typical) at V_{CC} V_{EE} = 3.0 V
 - 60 Ω (typical) at V_{CC} V_{EE} = 4.5 V
- Logic level translation:
 - \blacklozenge To enable 3 V logic to communicate with \pm 3 V analog signals
- Typical 'break before make' built in
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C



3. Ordering information

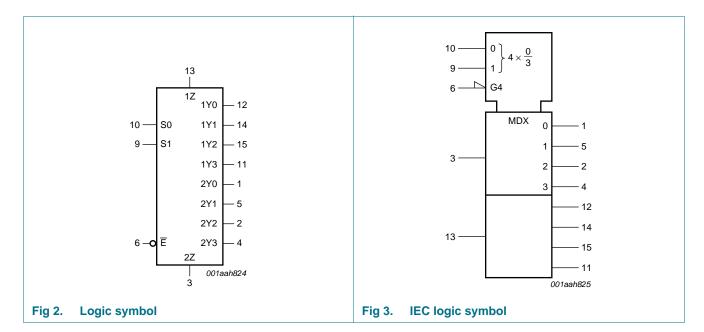
Table 1. Ordering information									
Type number	Package								
	Temperature range	Name	Description	Version					
74LV4052N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4					
74LV4052D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
74LV4052DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1					
74LV4052PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					

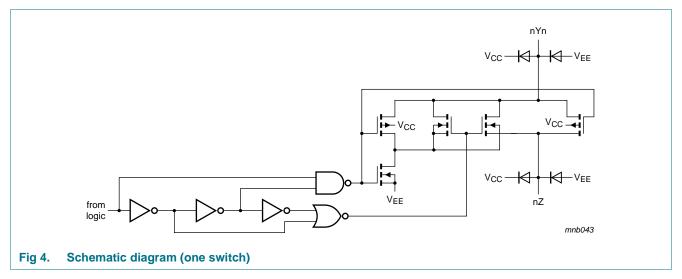
4. Functional diagram



74LV4052

Dual 4-channel analog multiplexer/demultiplexer



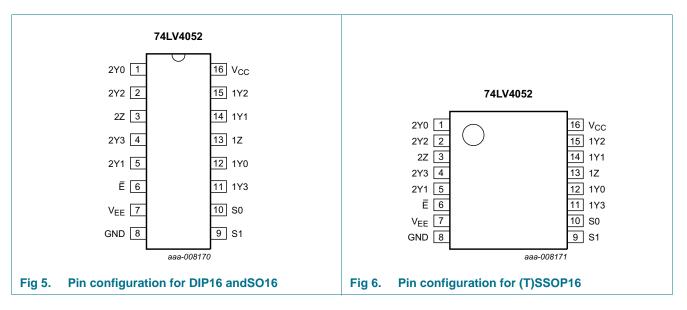


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5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
2Y0	1	independent input or output
2Y2	2	independent input or output
2Z	3	common input or output
2Y3	4	independent input or output
2Y1	5	independent input or output
Ē	6	enable input (active LOW)
V_{EE}	7	negative supply voltage
GND	8	ground (0 V)
S1	9	select logic input
S0	10	select logic input
1Y3	11	independent input or output
1Y0	12	independent input or output
1Z	13	common input or output
1Y1	14	independent input or output
1Y2	15	independent input or output
V _{CC}	16	positive supply voltage

6. Functional description

Table 3.	Function table ^[1]			
Input			Channel on	
E	S1	S0		
L	Ĺ	L	nY0 and nZ	
L	L	Н	nY1 and nZ	
L	Н	L	nY2 and nZ	
L	Н	Н	nY3 and nZ	
Н	Х	Х	none	

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		<u>[1]</u> –0.5	+7.0	V
I _{IK}	input clamping current	$V_{\rm I}$ < –0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	[2] _	±20	mA
I _{SK}	switch clamping current	V_{SW} < –0.5 V or V_{SW} > V_{CC} + 0.5 V	[2] _	±20	mA
I _{SW}	switch current	V_{SW} > –0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	[2] _	±25	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$	<u>[3]</u>		
		DIP16 package	-	750	mW
		SO16 package	-	500	mW
		SSOP16 and TSSOP16 package	-	400	mW

[1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows into terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current flows out of terminals nYn. In this case, there is no limit for the voltage drop across the switch, but the voltages at nYn and nZ may not exceed V_{CC} or V_{EE} .

[2] The minimum input voltage rating may be exceeded if the input current rating is observed.

[3] For DIP16 package: above 70 °C the value of P_{tot} derates linearly with 12 mW/K.

For SO16 package: above 70 °C the value of P_{tot} derates linearly with 8 mW/K.

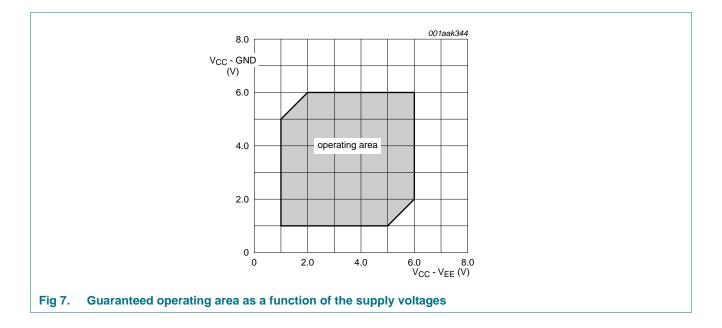
For SSOP16 and TSSOP16 packages: above 60 $^\circ$ C the value of P_{tot} derates linearly with 5.5 mW/K.

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8. Recommended operating conditions

Table 5.	Recommended operating conditions ^[1]								
Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
V _{CC}	supply voltage	see Figure 7	1	3.3	6	V			
VI	input voltage		0	-	V _{CC}	V			
V _{SW}	switch voltage		0	-	V _{CC}	V			
T _{amb}	ambient temperature	in free air	-40	-	+125	°C			
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.0 V to 2.0 V	-	-	500	ns/V			
		V_{CC} = 2.0 V to 2.7 V	-	-	200	ns/V			
		$V_{CC} = 2.7 \text{ V to } 6.0 \text{ V}$	-	-	100	ns/V			

[1] The static characteristics are guaranteed from V_{CC} = 1.2 V to 6.0 V. However, LV devices are guaranteed to function down to V_{CC} = 1.0 V (with input levels GND or V_{CC}).



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9. Static characteristics

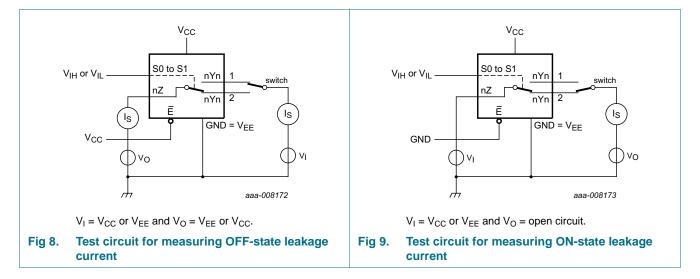
Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	–40 °C to +125 °C		
			Min	Typ <mark>[1]</mark>	Max	Min	Max		
√ _{IH}	HIGH-level input voltage	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V	
		$V_{CC} = 2.0 V$	1.4	-	-	1.4	-	V	
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V	
		$V_{CC} = 4.5 V$	3.15	-	-	3.15	-	V	
		V _{CC} = 6.0 V	4.20	-	-	4.20	-	V	
/ _{IL}	LOW-level input voltage	V _{CC} = 1.2 V	-	-	0.3	-	0.3	V	
		V _{CC} = 2.0 V	-	-	0.6	-	0.6	V	
		V_{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V	
		$V_{CC} = 4.5 V$	-	-	1.35	-	1.35	V	
		$V_{CC} = 6.0 V$	-	-	1.80	-	1.80	V	
	input leakage current	$V_I = V_{CC}$ or GND							
		$V_{CC} = 3.6 V$	-	-	1.0	-	1.0	μΑ	
		$V_{CC} = 6.0 V$	-	-	2.0	-	2.0	μΑ	
S(OFF)	OFF-state leakage current	$V_I = V_{IH}$ or V_{IL} ; see <u>Figure 8</u>							
		$V_{CC} = 3.6 V$	-	-	1.0	-	- 1.0	μΑ	
		$V_{CC} = 6.0 V$	-	-	2.0	-	2.0	μΑ	
S(ON)	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; see <u>Figure 9</u>							
		$V_{CC} = 3.6 V$	-	-	1.0	-	1.0	μΑ	
		$V_{CC} = 6.0 V$	-	-	2.0	-	2.0	μΑ	
СС	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A							
		$V_{CC} = 3.6 V$	-	-	20	-	40	μΑ	
		$V_{CC} = 6.0 V$	-	-	40	-	80	μΑ	
lcc	additional supply current	per input; V _I = V _{CC} – 0.6 V; V _{CC} = 2.7 V to 3.6 V	-	-	500	-	850	μA	
à	input capacitance		-	3.5	-	-	-	pF	
sw	switch capacitance	independent pins nYn	-	5	-	-	-	pF	
		common pins nZ	-	12	-	-	-	pF	

[1] Typical values are measured at T_{amb} = 25 °C.

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9.1 Test circuits

9.2 ON resistance

Table 7. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see <u>Figure 10</u> and <u>Figure 11</u>.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to	o +125 °C	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	1
R _{ON(peak)}	ON resistance (peak)	$V_I = 0 V$ to $V_{CC} - V_{EE}$						1	•
		V_{CC} = 1.2 V; I_{SW} = 100 μ A	[2]	-	-	-	-	-	Ω
		V_{CC} = 2.0 V; I_{SW} = 1000 μ A		-	145	325	-	375	Ω
		V_{CC} = 2.7 V; I_{SW} = 1000 μ A		-	90	200	-	235	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V;}$ $I_{SW} = 1000 \mu\text{A}$		-	80	180	-	210	Ω
		V_{CC} = 4.5 V; I_{SW} = 1000 μ A		-	60	135	-	160	Ω
		V_{CC} = 6.0 V; I_{SW} = 1000 μ A		-	55	125	-	145	Ω
ΔR_{ON}	ON resistance mismatch	$V_I = 0 V \text{ to } V_{CC} - V_{EE}$							
	between channels	V_{CC} = 1.2 V; I_{SW} = 100 μ A	[2]	-	-	-	-	-	Ω
		V_{CC} = 2.0 V; I_{SW} = 1000 μ A		-	5	-	-	-	Ω
		V_{CC} = 2.7 V; I_{SW} = 1000 μ A		-	4	-	-	-	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V;}$ $I_{SW} = 1000 \mu\text{A}$		-	4	-	-	-	Ω
		V_{CC} = 4.5 V; I_{SW} = 1000 μ A		-	3	-	-	-	Ω
		V_{CC} = 6.0 V; I_{SW} = 1000 μ A		-	2	-	-	-	Ω

Table 7. ON resistance ... continued

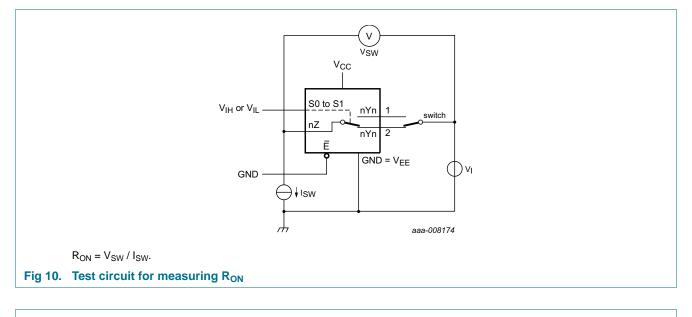
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see <u>Figure 10</u> and <u>Figure 11</u>.

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
R _{ON(rail)}	ON resistance (rail)	V _I = GND			I			
		$V_{CC} = 1.2 \text{ V}; \text{ I}_{SW} = 100 \mu\text{A}$ [2]	-	225	-	-	-	Ω
		V_{CC} = 2.0 V; I _{SW} = 1000 µA	-	110	235	-	270	Ω
		V_{CC} = 2.7 V; I_{SW} = 1000 μ A	-	70	145	-	165	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V;}$ $I_{SW} = 1000 \mu\text{A}$	-	60	130	-	150	Ω
		V_{CC} = 4.5 V; I _{SW} = 1000 µA	-	45	100	-	115	Ω
		V_{CC} = 6.0 V; I _{SW} = 1000 µA	-	40	85	-	100	Ω
R _{ON(rail)}	ON resistance (rail)	$V_I = V_{CC} - V_{EE}$						
		V _{CC} = 1.2 V; I _{SW} = 100 μA [2]	-	250	-	-	-	Ω
		V_{CC} = 2.0 V; I_{SW} = 1000 μ A	-	120	320	-	370	Ω
		V_{CC} = 2.7 V; I_{SW} = 1000 μ A	-	75	195	-	225	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V;}$ $I_{SW} = 1000 \mu\text{A}$	-	70	175	-	205	Ω
		V_{CC} = 4.5 V; I _{SW} = 1000 µA	-	50	130	-	150	Ω
		$V_{CC} = 6.0 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$	-	45	120	-	135	Ω

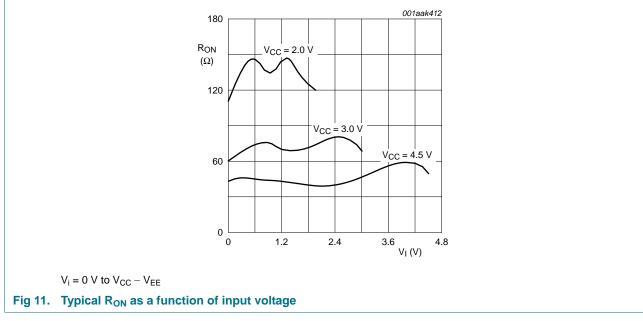
[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

[2] When supply voltages (V_{CC} - V_{EE}) near 1.2 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 1.2 V, only use these devices for transmitting digital signals.

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9.3 On resistance waveform and test circuit



Dual 4-channel analog multiplexer/demultiplexer

10. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit, see Figure 14.

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	-40 °C to	o +125 °C	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
t _{pd}	propagation delay	nYn to nZ, nZ to nYn; see Figure 12	[2]						
		$V_{CC} = 1.2 V$		-	25	-	-	-	ns
		$V_{CC} = 2.0 V$		-	9	17	-	20	ns
		$V_{CC} = 2.7 V$		-	6	13	-	15	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	[3]	-	5	10	-	12	ns
		$V_{CC} = 4.5 V$		-	4	9	-	10	ns
		$V_{CC} = 6.0 V$		-	3	7	-	8	ns
t _{en}	enable time	E, Sn to nYn, nZ; see Figure 13	[2]						
		$V_{CC} = 1.2 V$		-	190	-	-	-	ns
		$V_{CC} = 2.0 V$		-	65	121	-	146	ns
		$V_{CC} = 2.7 V$		-	48	89	-	108	ns
		V_{CC} = 3.0 V to 3.6 V; C _L = 15 pF	[3]	-	30	-	-	-	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	[3]	-	36	71	-	86	ns
		$V_{CC} = 4.5 V$		-	32	60	-	73	ns
		$V_{CC} = 6.0 V$		-	25	46	-	56	ns
t _{dis}	disable time	E, Sn to nYn, nZ; see Figure 13	[2]						
		$V_{CC} = 1.2 V$		-	125	-	-	-	ns
		$V_{CC} = 2.0 V$		-	43	80	-	95	ns
		$V_{CC} = 2.7 V$		-	33	59	-	71	ns
		V_{CC} = 3.0 V to 3.6 V; C _L = 15 pF	[3]	-	22	-	-	-	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	[3]	-	26	48	-	57	ns
		$V_{CC} = 4.5 V$		-	23	41	-	49	ns
		$V_{CC} = 6.0 V$		-	18	32	-	38	ns
C _{PD}	power dissipation capacitance	C_L = 50 pF; f _i = 1 MHz; V _I = GND to V _{CC}	<u>[4]</u>	-	57	-	-	-	pF

[1] All typical values are measured at T_{amb} = 25 °C.

 t_{dis} is the same as t_{PLZ} and $t_{\text{PHZ}}.$

[3] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V).

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma((C_{L} + C_{sw}) \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz, f_o = output frequency in MHz

 C_L = output load capacitance in pF

 C_{sw} = maximum switch capacitance in pF;

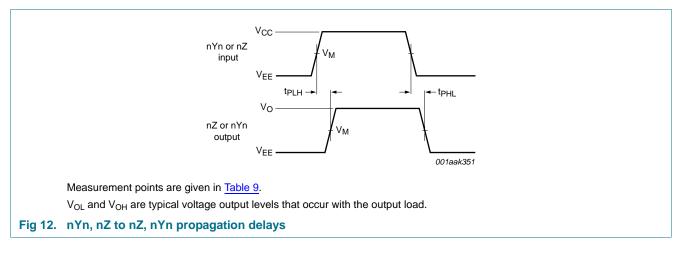
 V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of the outputs.

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10.1 Waveforms



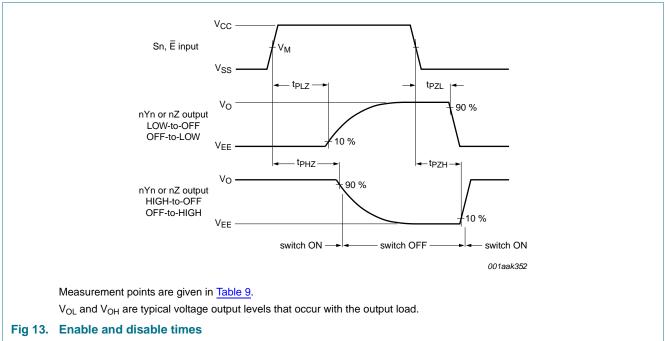


Table 9. Measurement points

Supply voltage	Input	Output
V _{cc}	V _M	V _M
< 2.7 V	0.5V _{CC}	0.5V _{CC}
2.7 V to 3.6 V	1.5 V	1.5 V
> 3.6 V	0.5V _{CC}	0.5V _{CC}

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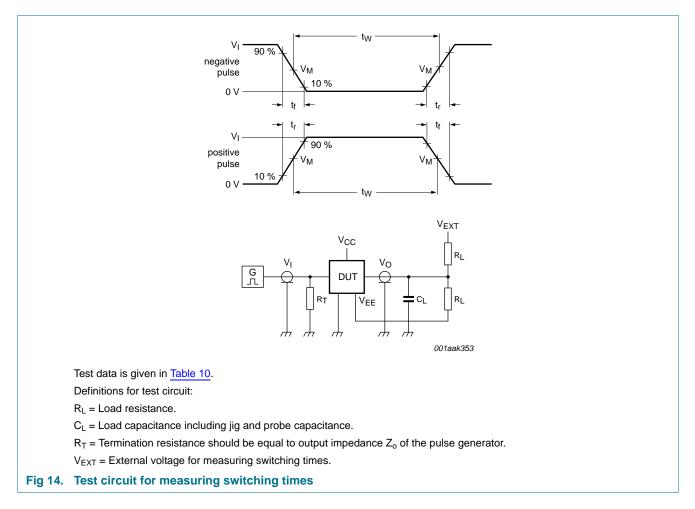


Table 10. Test data

Supply voltage	Input		Load	Load		V _{EXT}			
V _{cc}	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}		
< 2.7 V	V _{CC}	≤ 6 ns	50 pF	1 kΩ	open	V_{EE}	2V _{CC}		
2.7 V to 3.6 V	2.7 V	≤ 6 ns	15 pF, 50 pF	1 kΩ	open	V_{EE}	2V _{CC}		
> 3.6 V	V _{CC}	≤ 6 ns	50 pF	1 kΩ	open	V_{EE}	2V _{CC}		

10.2 Additional dynamic parameters

Table 11. Additional dynamic characteristics

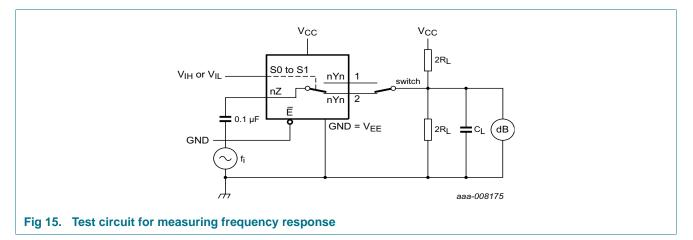
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 6.0$ ns; $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic	$f_i = 1 \text{ kHz}; C_L = 50 \text{ pF}; R_L = 10 \text{ k}\Omega; \text{ see } \frac{\text{Figure } 19}{10 \text{ k}}$				
	distortion	V _{CC} = 3.0 V; V _I = 2.75 V (p-p)	-	0.8	-	%
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 5.5 \text{ V} \text{ (p-p)}$	-	0.4	-	%
		$f_i = 10 \text{ kHz}; C_L = 50 \text{ pF}; R_L = 10 \text{ k}\Omega; \text{ see } \frac{\text{Figure 19}}{10 \text{ kHz}}$				
		V _{CC} = 3.0 V; V _I = 2.75 V (p-p)	-	2.4	-	%
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 5.5 \text{ V} (p-p)$	-	1.2	-	%
f _(-3dB)	-3 dB frequency	$C_L = 50 \text{ pF}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure } 15}{1000}$	<u>[1]</u>			
	response	$V_{CC} = 3.0 V$	-	180	-	MHz
		$V_{CC} = 6.0 V$	-	200	-	MHz
α_{iso}	isolation (OFF-state)	$f_i = 1 \text{ MHz}; C_L = 50 \text{ pF}; R_L = 600 \Omega; \text{ see } \frac{\text{Figure } 17}{1000}$	[2]			
		$V_{CC} = 3.0 V$	-	-50	-	dB
		$V_{CC} = 6.0 V$	-	-50	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 MHz; C_L = 50 pF; R_L = 600 Ω; see Figure 20$				
		$V_{CC} = 3.0 V$	-	0.11	-	V
		$V_{CC} = 6.0 V$	-	0.12	-	V
Xtalk	crosstalk	between switches; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 600 \Omega$; see <u>Figure 21</u>	<u>[2]</u>			
		$V_{CC} = 3.0 V$	-	-60	-	dB
		$V_{CC} = 6.0 V$	-	-60	-	dB

[1] To obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 50 Ω), adjust f_i voltage.

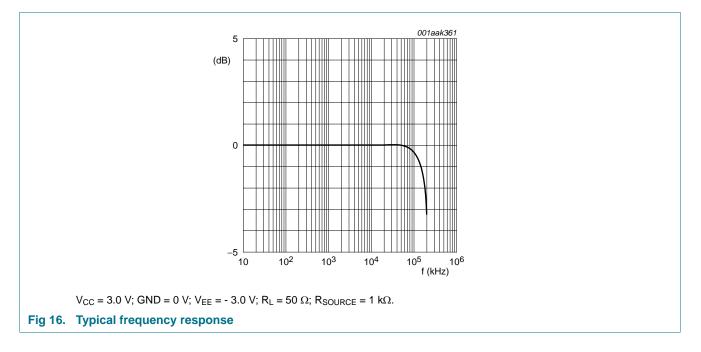
[2] To obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 600 Ω), adjust f_i voltage.

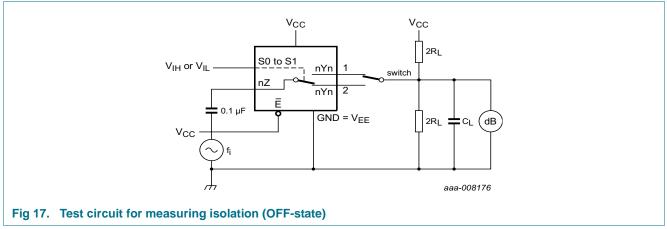
10.2.1 Test circuits



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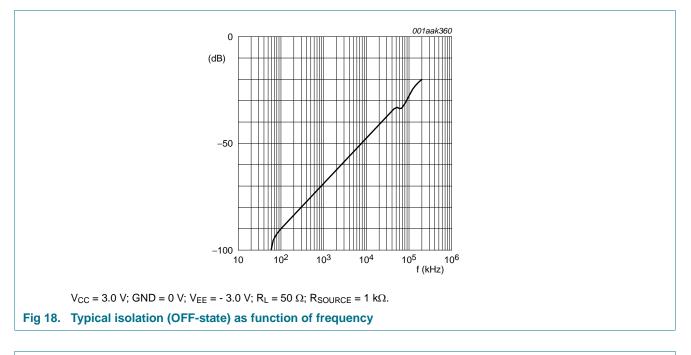
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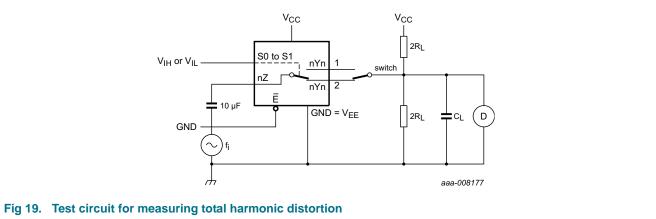




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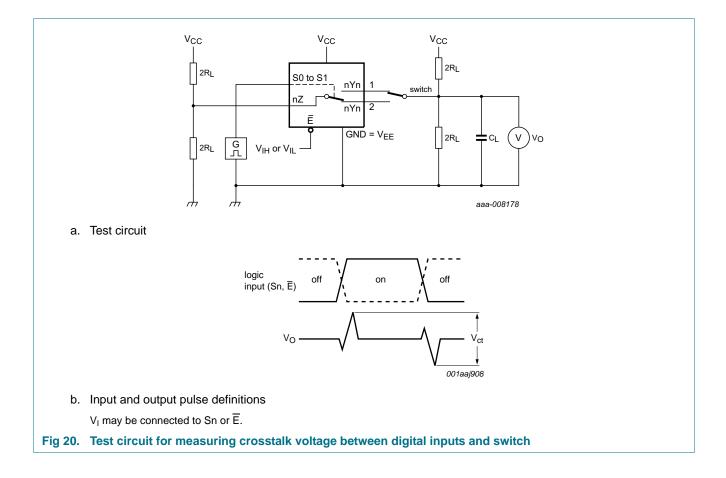
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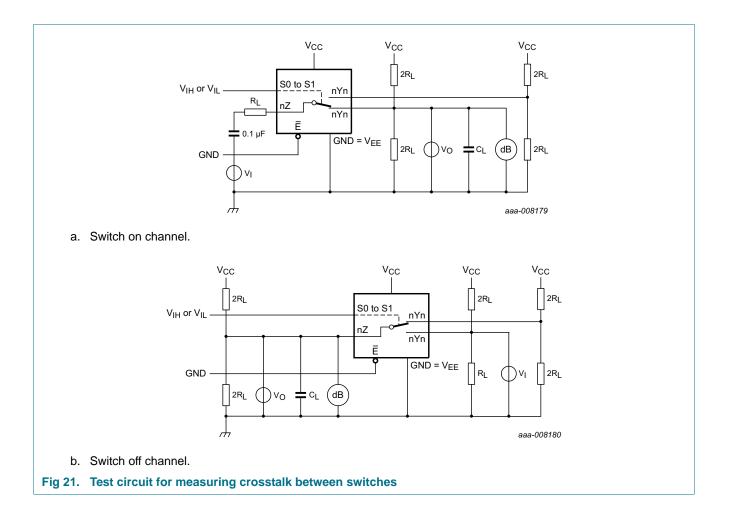
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11. Package outline

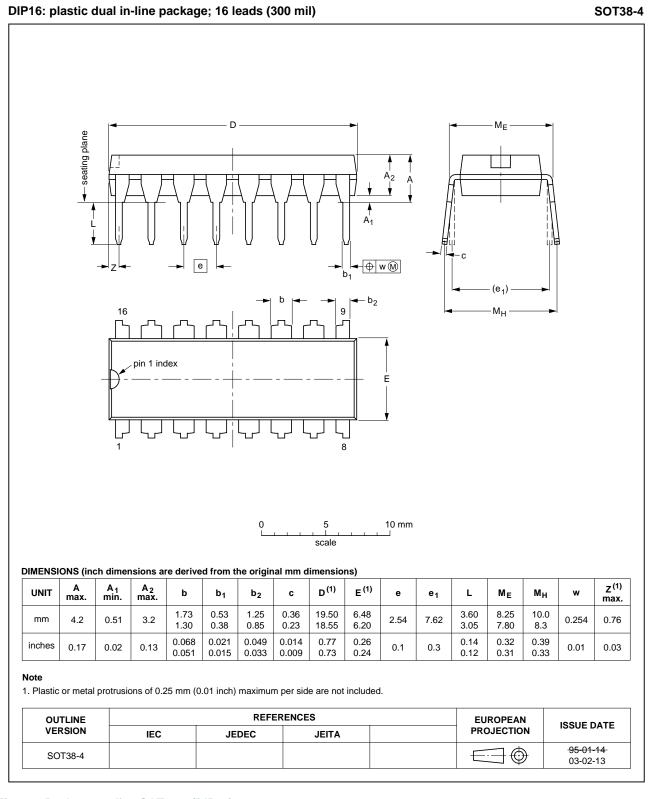


Fig 22. Package outline SOT38-4 (DIP16)

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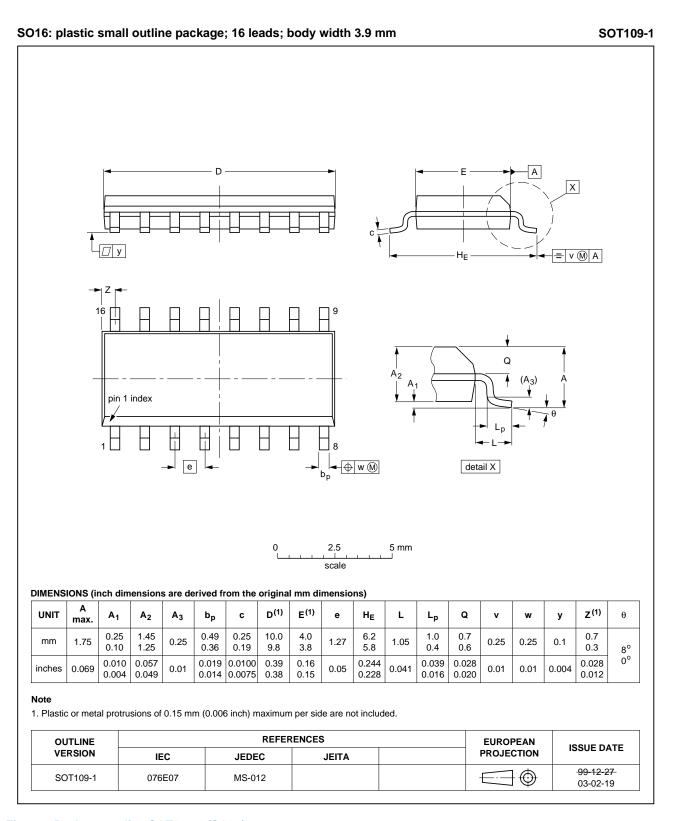


Fig 23. Package outline SOT109-1 (SO16)

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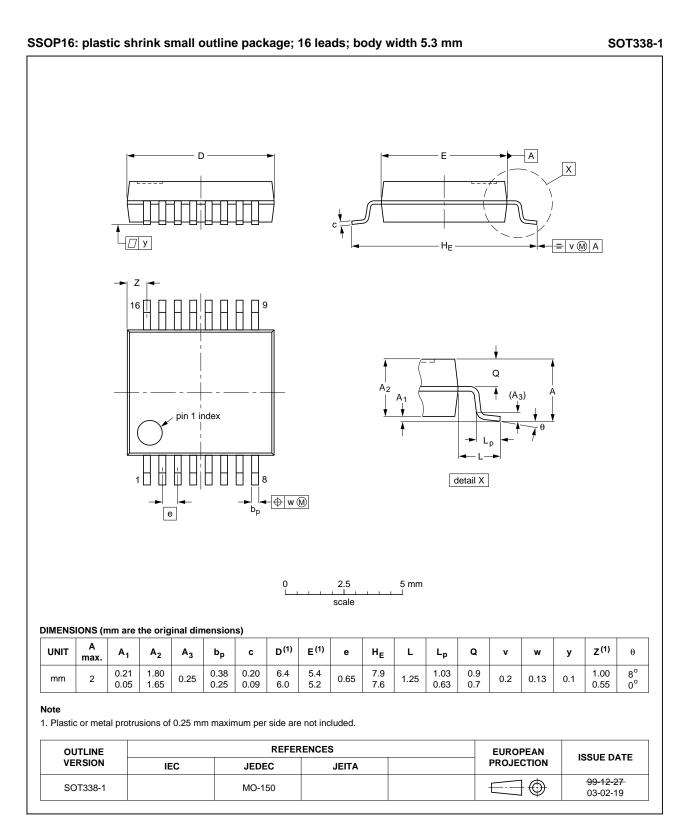


Fig 24. Package outline SOT338-1 (SSOP16)

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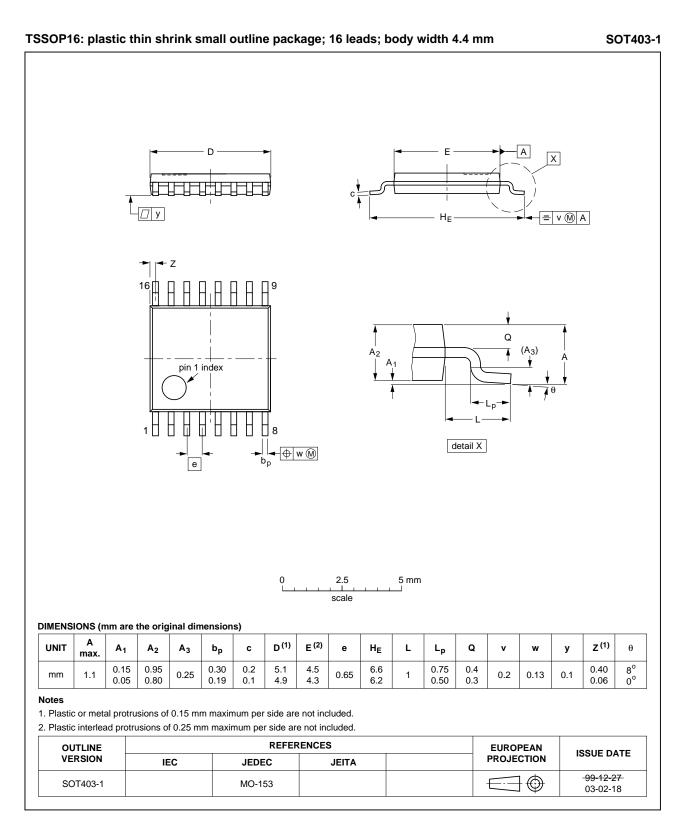


Fig 25. Package outline SOT403-1 (TSSOP16)

12. Abbreviations

Table 12. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal-Oxide Semiconductor			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			
TTL	Transistor-Transistor Logic			

13. Revision history

Table 13.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74LV4052 v.4	20130701	Product data sheet	-	74LV4052 v.3	
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 				
74LV4052 v.3	19980623	Product specification	-	74LV4052 v.2	
74LV4052 v.2	19970715	Product specification	-	-	

14. Legal information

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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